

## 1 470 TO 1 610 nm FOR 2.5 Gb/s, CWDM InGaAsP MQW-DFB LASER DIODE

### DESCRIPTION

The NX6508 Series is a 1 470 to 1 610 nm Multiple Quantum Well (MQW) structured Distributed Feed-Back (DFB) laser diode with InGaAs monitor PIN-PD. These devices are ideal for 2.5 Gb/s CWDM application.

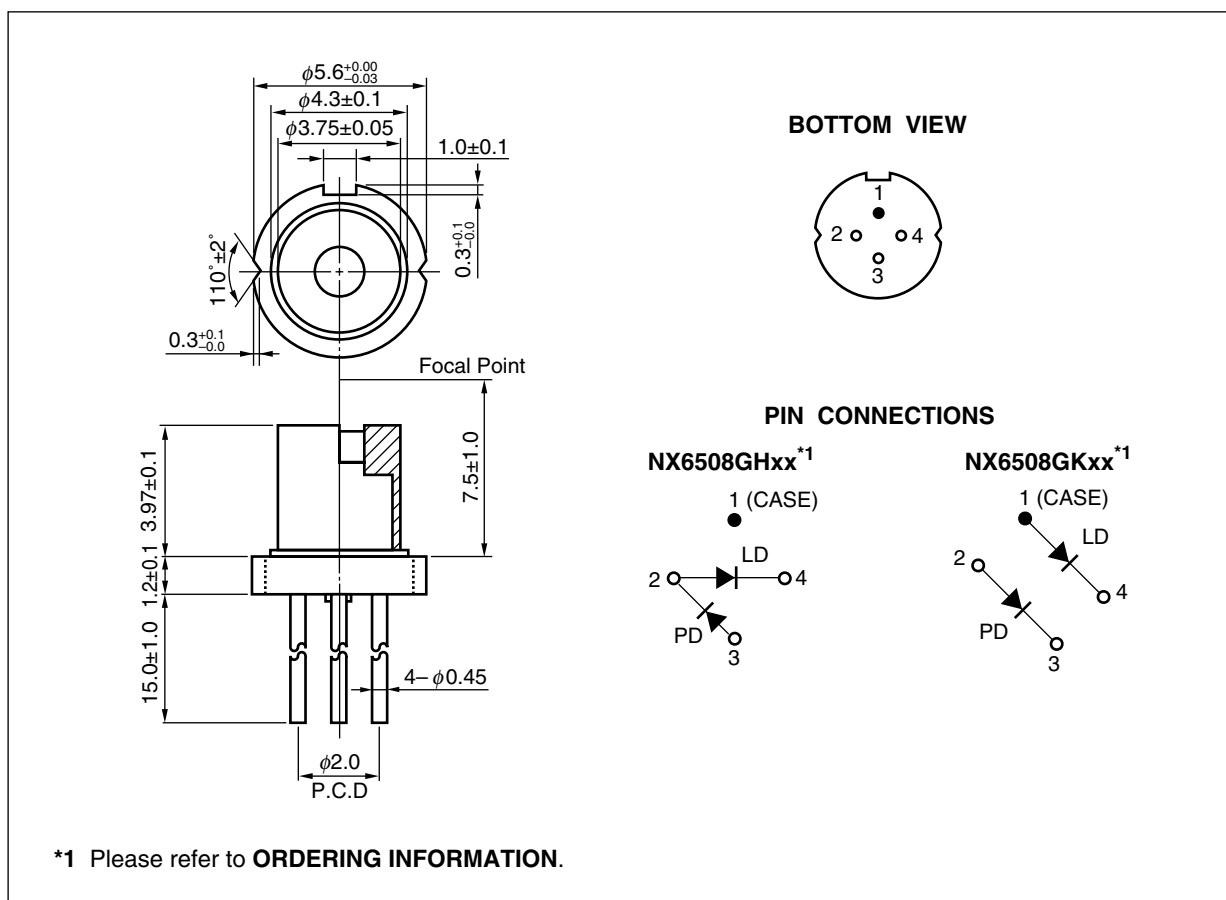
### FEATURES

- |                                      |  |
|--------------------------------------|--|
| • Optical output power               | $P_o = 5.0 \text{ mW}$   |
| • Peak emission wavelength           | $\lambda_p = 1\,470 \text{ to } 1\,610 \text{ nm}$ (Based on CWDM) |
| • Low threshold current              | $I_{th} = 10 \text{ mA}$   |
| • High speed                         | $t_r = 100 \text{ ps MAX.}$<br>$t_f = 150 \text{ ps MAX.}$         |
| • Side mode suppression ratio        | SMSR = 40 dB   |
| ★ • Operating case temperature range | $T_c = -20 \text{ to } +85^\circ\text{C}$                          |
| • InGaAs monitor PIN-PD              |  |
| • CAN package                        | $\phi 5.6 \text{ mm}$  |
| • Based on Telcordia reliability     |  |



The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version.  
Not all devices/types available in every country. Please check with local NEC Compound Semiconductor Devices representative for availability and additional information.

PACKAGE DIMENSIONS (UNIT: mm)



# ORDERING INFORMATION

NX6508 □□xx

Wavelength code : Refer to **Table A**

Package code : Refer to **PACKAGE DIMENSIONS**

# ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Ratings	Unit
Optical Output Power	$P_o$	10	mW
Forward Current of LD	$I_F$	150	mA
Reverse Voltage of LD	$V_R$	2.0	V
Forward Current of PD	$I_F$	2.0	mA
Reverse Voltage of PD	$V_R$	15	V
★ Operating Case Temperature	$T_C$	-20 to +85	°C
Storage Temperature	$T_{stg}$	-40 to +85	°C
Lead Soldering Temperature	$T_{sld}$	350 (3 sec.)	°C
Relative Humidity (noncondensing)	RH	85	%

★ **ELECTRO-OPTICAL CHARACTERISTICS (T<sub>c</sub> = -20 to +85°C, unless otherwise specified)**

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Optical Output Power	P <sub>o</sub>	CW		5.0		mW
Operating Voltage	V <sub>op</sub>	P <sub>o</sub> = 5.0 mW		1.1	1.6	V
Threshold Current	I <sub>th</sub>	T <sub>c</sub> = 25°C		10	20	mA
					50	
Differential Efficiency	η <sub>d</sub>	P <sub>o</sub> = 5.0 mW, T <sub>c</sub> = 25°C	0.18	0.25		W/A
		P <sub>o</sub> = 5.0 mW	0.10			
Temperature Dependence of Differential Efficiency	Δη <sub>d</sub>	Δη <sub>d</sub> = 10 log $\frac{\eta_d (@ T_c^\circ\text{C})}{\eta_d (@ 25^\circ\text{C})}$	-3.0	-1.6		dB
Peak Emission Wavelength	λ <sub>p</sub>	P <sub>o</sub> = 5.0 mW, T <sub>c</sub> = 35°C	λ <sub>p</sub> -2	λ <sub>p</sub> +1	λ <sub>p</sub> +2	nm
Temperature Dependence of Peak Emission Wavelength	Δλ/ΔT	CW	0.08	0.1	0.12	nm/°C
Side Mode Suppression Ratio	SMSR	P <sub>o</sub> = 5.0 mW	30	40		dB
Rise Time	t <sub>r</sub>	20-80%, P <sub>o</sub> = 5.0 mW			100	ps
Fall Time	t <sub>f</sub>	80-20%, P <sub>o</sub> = 5.0 mW			150	ps
Monitor Current	I <sub>m</sub>	V <sub>R</sub> = 1.5 V, P <sub>o</sub> = 5.0 mW	200	1 000	2 000	μA
Monitor Dark Current	I <sub>D</sub>	V <sub>R</sub> = 1.5 V, T <sub>c</sub> = 25°C		0.1	10	nA
		V <sub>R</sub> = 1.5 V		10	100	

\*1 Available for CWDM Wavelengths based on ITU-T recommendations

λ<sub>p</sub> = 1 470, 1 490, 1 510, 1 530, 1 550, 1 570, 1 590, 1 610 nm

Please refer to **Table A**.

★ **Table A: CWDM wavelength code (@ T<sub>c</sub> = 35°C)**

Wavelength Code	MIN. (nm)	TYP. (nm)	MAX. (nm)
47	1 468	1 470	1 472
49	1 488	1 490	1 492
51	1 508	1 510	1 512
53	1 528	1 530	1 532
55	1 548	1 550	1 552
57	1 568	1 570	1 572
59	1 588	1 590	1 592
61	1 608	1 610	1 612

LD CAN PACKAGES FAMILY FOR OPTICAL FIBER COMMUNICATIONS

Part Number	Absolute Maximum Ratings		Electro-Optical Characteristics (T <sub>c</sub> = 25°C)				Application	Package
	T <sub>C</sub> (°C)	T <sub>stg</sub> (°C)	I <sub>th</sub> (mA)	P <sub>o</sub> (mW)	λ (nm)			
			TYP.	TYP.	MIN.	MAX.		
NX5304 Series	−40 to +85	−40 to +85	10	5	1 263	1 360	156 Mb/s: STM-1 (I-1, S-1.1, L-1.1)	CAN
							622 Mb/s: STM-4 (I-4, S-4.1)	
							1.25 Gb/s: GbE	
NX5306 Series	−40 to +85	−40 to +85	10	5	1 263	1 360	156 Mb/s: STM-1 (I-1, S-1.1, L-1.1)	CAN
							622 Mb/s: STM-4 (I-4, S-4.1)	
							1.25 Gb/s: GbE	
NX5307 Series	−40 to +85	−40 to +85	10	10	1 266	1 360	2.5 Gb/s: STM-16	CAN
NX5501 Series	−20 to +85	−40 to +85	8	5	1 480	1 580	For FTTH	CAN
NX5504 Series	−20 to +85	−40 to +85	8	5	1 480	1 580	For FTTH	CAN
NX6306 Series	−40 to +85	−40 to +85	10	5	1 280	1 335	156 Mb/s: STM-1 (I-1, S-1.1, L-1.1)	CAN
							622 Mb/s: STM-4 (I-4, S-4.1, L-4.1)	
							1.25 Gb/s: GbE	
NX6307 Series	−20 to +85	−40 to +85	10	7	1 280	1 335	2.5 Gb/s: STM-16 (S-16.1, L-16.1)	CAN
NX6504 Series	−10 to +85	−40 to +85	12	5	1 530	1 570	156 Mb/s: STM-1	CAN
							622 Mb/s: STM-4	
NX6508 Series	−20 to +85	−40 to +85	10	5	λ <sub>p</sub> −2 <sup>±1</sup>	λ <sub>p</sub> +2 <sup>±1</sup>	For CWDM	CAN
NX6509 Series	−20 to +85	−40 to +85	10	5	1 530	1 570	2.5 Gb/s: STM-16 (L-16.2)	CAN

★ \*1 T<sub>c</sub> = 35°C, λ<sub>p</sub> = 1 470, 1 490, 1 510, 1 530, 1 550, 1 570, 1 590, 1 610 nm

**REFERENCE**

Document Name	Document No.
OPTICAL SEMICONDUCTOR DEVICES FOR FIBEROPTIC COMMUNICATIONS SELECTION GUIDE	PL10161E
Opto-Electronics Devices Pamphlet	PX10160E

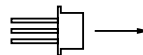
- **The information in this document is current as of March, 2004. The information is subject to change without notice. For actual design-in, refer to the latest publications of NEC's data sheets or data books, etc., for the most up-to-date specifications of NEC semiconductor products. Not all products and/or types are available in every country. Please check with an NEC sales representative for availability and additional information.**
- No part of this document may be copied or reproduced in any form or by any means without prior written consent of NEC. NEC assumes no responsibility for any errors that may appear in this document.
- NEC does not assume any liability for infringement of patents, copyrights or other intellectual property rights of third parties by or arising from the use of NEC semiconductor products listed in this document or any other liability arising from the use of such products. No license, express, implied or otherwise, is granted under any patents, copyrights or other intellectual property rights of NEC or others.
- Descriptions of circuits, software and other related information in this document are provided for illustrative purposes in semiconductor product operation and application examples. The incorporation of these circuits, software and information in the design of customer's equipment shall be done under the full responsibility of customer. NEC assumes no responsibility for any losses incurred by customers or third parties arising from the use of these circuits, software and information.
- While NEC endeavours to enhance the quality, reliability and safety of NEC semiconductor products, customers agree and acknowledge that the possibility of defects thereof cannot be eliminated entirely. To minimize risks of damage to property or injury (including death) to persons arising from defects in NEC semiconductor products, customers must incorporate sufficient safety measures in their design, such as redundancy, fire-containment, and anti-failure features.
- NEC semiconductor products are classified into the following three quality grades:  
 "Standard", "Special" and "Specific". The "Specific" quality grade applies only to semiconductor products developed based on a customer-designated "quality assurance program" for a specific application. The recommended applications of a semiconductor product depend on its quality grade, as indicated below. Customers must check the quality grade of each semiconductor product before using it in a particular application.  
 "Standard": Computers, office equipment, communications equipment, test and measurement equipment, audio and visual equipment, home electronic appliances, machine tools, personal electronic equipment and industrial robots  
 "Special": Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support)  
 "Specific": Aircraft, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems and medical equipment for life support, etc.  
 The quality grade of NEC semiconductor products is "Standard" unless otherwise expressly specified in NEC's data sheets or data books, etc. If customers wish to use NEC semiconductor products in applications not intended by NEC, they must contact an NEC sales representative in advance to determine NEC's willingness to support a given application.  
 (Note)  
 (1) "NEC" as used in this statement means NEC Corporation, NEC Compound Semiconductor Devices, Ltd. and also includes its majority-owned subsidiaries.  
 (2) "NEC semiconductor products" means any semiconductor product developed or manufactured by or for NEC (as defined above).

M8E 00.4-0110

SAFETY INFORMATION ON THIS PRODUCT



SEMICONDUCTOR LASER



AVOID EXPOSURE-Invisible  
Laser Radiation is emitted from  
this aperture

<div>Warning</div> <div>Laser Beam</div>	<p>A laser beam is emitted from this diode during operation. The laser beam, visible or invisible, directly or indirectly, may cause injury to the eye or loss of eyesight.</p> <ul style="list-style-type: none"> <li>• Do not look directly into the laser beam.</li> <li>• Avoid exposure to the laser beam, any reflected or collimated beam.</li> </ul>
<div>Caution</div> <div>GaAs Products</div>	<p>This product uses gallium arsenide (GaAs). GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points.</p> <ul style="list-style-type: none"> <li>• Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below.                             <ol style="list-style-type: none"> <li>1. Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials.</li> <li>2. Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal.</li> </ol> </li> <li>• Do not burn, destroy, cut, crush, or chemically dissolve the product.</li> <li>• Do not lick the product or in any way allow it to enter the mouth.</li> </ul>

► For further information, please contact

**NEC Compound Semiconductor Devices, Ltd.** <http://www.ncsd.necel.com/>

E-mail: [salesinfo@ml.ncsd.necel.com](mailto:salesinfo@ml.ncsd.necel.com) (sales and general)

[techinfo@ml.ncsd.necel.com](mailto:techinfo@ml.ncsd.necel.com) (technical)

5th Sales Group, Sales Division TEL: +81-44-435-1588 FAX: +81-44-435-1579

**NEC Compound Semiconductor Devices Hong Kong Limited**

E-mail: [ncsd-hk@elhk.nec.com.hk](mailto:ncsd-hk@elhk.nec.com.hk) (sales, technical and general)

Hong Kong Head Office TEL: +852-3107-7303 FAX: +852-3107-7309

Taipei Branch Office TEL: +886-2-8712-0478 FAX: +886-2-2545-3859

Korea Branch Office TEL: +82-2-558-2120 FAX: +82-2-558-5209

**NEC Electronics (Europe) GmbH** <http://www.ee.nec.de/>

TEL: +49-211-6503-0 FAX: +49-211-6503-1327

**California Eastern Laboratories, Inc.** <http://www.cel.com/>

TEL: +1-408-988-3500 FAX: +1-408-988-0279